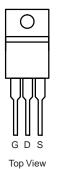


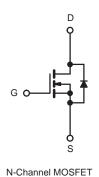
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N-Channel 100 V (D-S) MOSFET

PRODUCT	SUMMARY		
V _{DS} (V)	R _{DS(on)} (Ω) TYP.	I _D (A)	Q _g (TYP.)
100	0.0036 at V_{GS} = 10 V	180	53.5 nC
100	0.0039 at V_{GS} = 7.5 V	159	33.5 110

TO-220AB





• Maximum 175 °C junction temperature

100 % R_g and UIS tested

APPLICATIONS

- Power supplies:
 - Uninterruptible power supplies
 - AC/DC switch-mode power supplies
 - Lighting
- Synchronous rectification
- DC/DC converter
- Motor drive switch
- DC/AC inverter
- Battery management

ABSOLUTE MAXIMUM RATINGS	$(T_C = 25 \ ^{\circ}C, \text{ unless other})$	wise noted)			
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	100	N	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current (T. 150 °C)	T _C = 25 °C		180		
Continuous Drain Current ($T_J = 150 \ ^\circ$ C)	T _C = 125 °C	I _D	90	•	
Pulsed Drain Current (t = 100 μs)		I _{DM}	700	A	
Avalanche Current	L = 0.1 mH	I _{AS}	50		
Single Avalanche Energy ^a	L = 0.1 MH	E _{AS}	438	mJ	
Maximum Power Dissipation ^a	T _C = 25 °C	D	375 ^b	w	
	T _C = 125 °C	– P _D	125 ^b		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	°C/W
Junction-to-Case (Drain)	R _{thJC}	0.75	0/10

Notes

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR4 material).

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static	1					
Drain-Source Breakdown Voltage	V _{DS}	V_{GS} = 0 V, I_D = 250 μ A	100	-	-	- v
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2	-	4	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	-	-	1	μA
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 100 V, V_{GS} = 0 V, T_{J} = 125 °C	-	-	100	
		$V_{DS} = 100 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	2	mA
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \geq 10 \text{ V}, V_{GS} = 10 \text{ V}$	90	-	-	А
Ducia Course On Otata Decistance &	D	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	0.0036	0.0039	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 7.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$	-	0.0039	0.0042	
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 30 A	-	85	-	S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 50 V, f = 1 MHz	-	3330	-	pF
Output Capacitance	C _{oss}		-	1395	-	
Reverse Transfer Capacitance	C _{rss}		-	95	-	
Total Gate Charge ^c	Qg		-	53.5	81	nC
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	-	14.5	-	
Gate-Drain Charge ^c	Q _{gd}		-	13.2	-	
Gate Resistance	Rg	f = 1 MHz	0.9	1.9	3.8	Ω
Turn-On Delay Time ^c	t _{d(on)}		-	13	26	
Rise Time ^c	tr	V_{DD} = 50 V, R_L = 1.67 Ω	-	22	44	ns
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 30$ Å, $V_{GEN} = 10$ V, $R_g = 1$ Ω	-	27	54	
Fall Time ^c	t _f		-	9	18	
Drain-Source Body Diode Ratings an	nd Characteri	stics ^b (T _C = 25 °C)				
Pulsed Current (t = 100 µs)	I _{SM}		-	-	700	А
Forward Voltage ^a	V _{SD}	$I_F = 30 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.86	1.4	V
Reverse Recovery Time	t _{rr}		-	88	176	ns
Peak Reverse Recovery Charge	I _{RM(REC)}	I _F = 30 A, di/dt = 100 A/μs	-	5	10	А
Reverse Recovery Charge	Q _{rr}		-	0.22	0.44	μC

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},$ duty cycle $\leq 2~\%.$

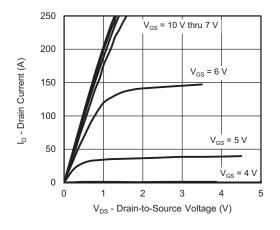
b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

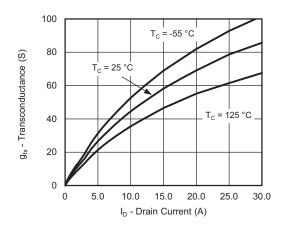
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



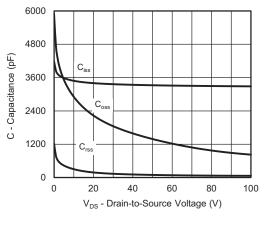
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



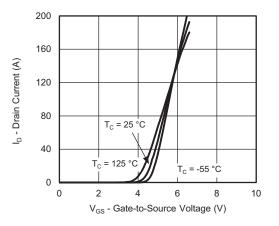
Output Characteristics



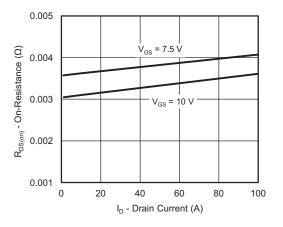
Transconductance



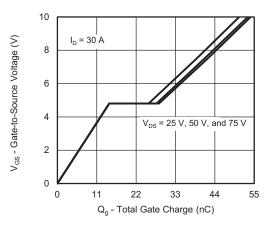
Capacitance



Transfer Characteristics



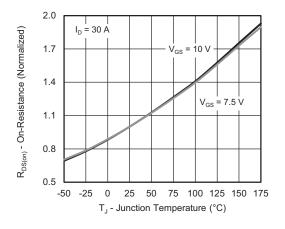
On-Resistance vs. Drain Current



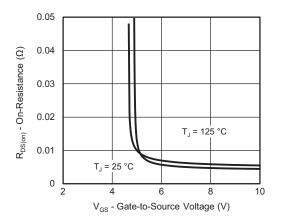
Gate Charge



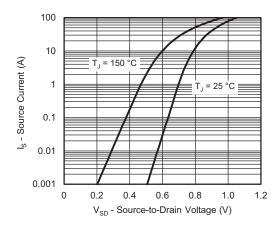
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



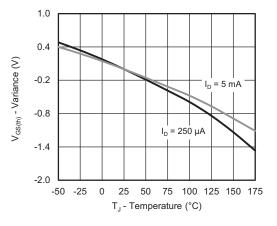
On-Resistance vs. Junction Temperature



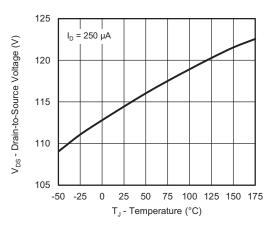
On-Resistance vs. Gate-to-Source Voltage



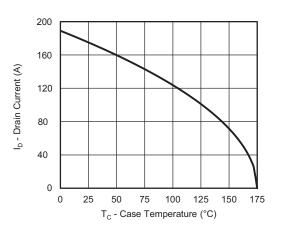
Source Drain Diode Forward Voltage



Threshold Voltage



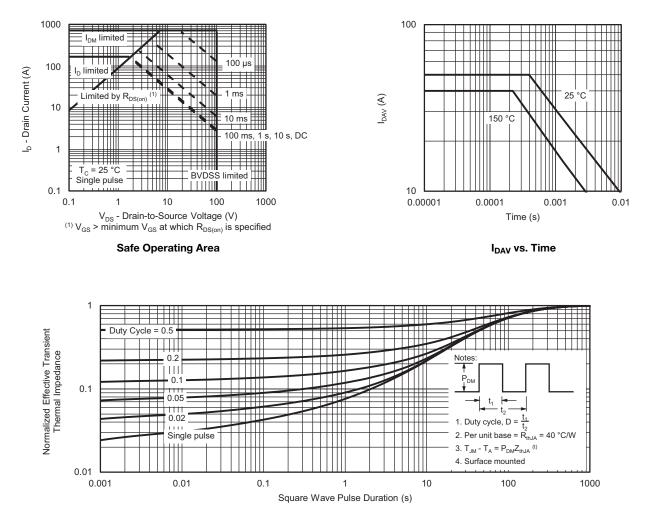
Drain Source Breakdown vs. Junction Temperature



Current De-Rating



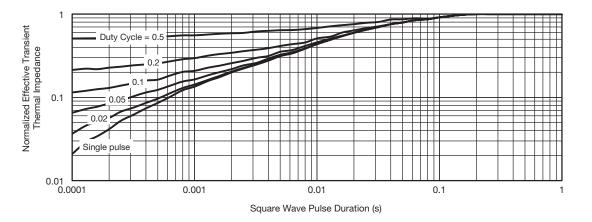
THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

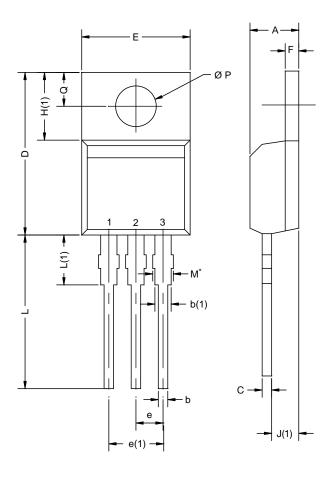
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.



Package Information www.din-tek.jp

TO-220AB



MIN.	MAX.	MIN.	MAX.
4.25	4.65	0.167	0.183
0.69	1.01	0.027	0.040
1.20	1.73	0.047	0.068
0.36	0.61	0.014	0.024
14.85	15.49	0.585	0.610
10.04	10.51	0.395	0.414
2.41	2.67	0.095	0.105
4.88	5.28	0.192	0.208
1.14	1.40	0.045	0.055
6.09	6.48	0.240	0.255
2.41	2.92	0.095	0.115
13.35	14.02	0.526	0.552
3.32	3.82	0.131	0.150
3.54	3.94	0.139	0.155
2.60	3.00	0.102	0.118
	4.25 0.69 1.20 0.36 14.85 10.04 2.41 4.88 1.14 6.09 2.41 13.35 3.32 3.54 2.60	4.25 4.65 0.69 1.01 1.20 1.73 0.36 0.61 14.85 15.49 10.04 10.51 2.41 2.67 4.88 5.28 1.14 1.40 6.09 6.48 2.41 2.92 13.35 14.02 3.32 3.82 3.54 3.94	4.254.650.1670.691.010.0271.201.730.0470.360.610.01414.8515.490.58510.0410.510.3952.412.670.0954.885.280.1921.141.400.0456.096.480.2402.412.920.09513.3514.020.5263.323.820.1313.543.940.1392.603.000.102

Notes

* M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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